# BLL6G1214L-250

LDMOS L-band radar power transistor

**AMPLEON** 

Rev. 3 — 28 January 2016

Product data sheet

### 1. Product profile

#### 1.1 General description

250 W LDMOS power transistor intended for L-band radar applications in the 1.2 GHz to 1.4 GHz range.

#### Table 1. Test information

Typical RF performance at  $T_{case}$  = 25 °C;  $t_p$  = 1 ms;  $\delta$  = 10 %;  $I_{Dq}$  = 150 mA; in a class-AB production test circuit.

Test signal	f	V <sub>DS</sub>	$P_L$	G <sub>p</sub>	$\eta_{D}$	t <sub>r</sub>	t <sub>f</sub>
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	1.2 to 1.4	36	250	15	45	15	5

#### 1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (1.2 GHz to 1.4 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

 L-band power amplifiers for radar applications in the 1.2 GHz to 1.4 GHz frequency range

### 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		
2	gate		1
3	source		2
			3 sym112

<sup>[1]</sup> Connected to flange

## 3. Ordering information

Table 3. Ordering information

Type number	Packag	e			
	Name	Description	Version		
BLL6G1214L-250	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT502A		

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	89	٧
$V_{GS}$	gate-source voltage		-0.5	+11	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j\text{-case})}$	thermal resistance from junction to case	T <sub>case</sub> = 85 °C; P <sub>L</sub> = 250 W	0.244	K/W
Z <sub>th(j-c)</sub>	transient thermal impedance	$T_{case} = 85  ^{\circ}C; P_{L} = 250  W$ [1]		
	from junction to case	t <sub>p</sub> = 1000 μs; δ = 10 %	0.124	K/W
		$t_p$ = 100 $\mu$ s; $\delta$ = 10 %	0.059	K/W
		$t_p$ = 200 $\mu$ s; $\delta$ = 10 %	0.077	K/W
		$t_p$ = 300 $\mu$ s; $\delta$ = 10 %	0.088	K/W
		$t_p$ = 100 $\mu$ s; $\delta$ = 20 %	0.078	K/W

<sup>[1]</sup> Z<sub>th(j-c)</sub> values are calculated from results obtained with ANSYS simulations and confirmed with IR measurements during development stage. During production: guaranteed by design.

### 6. Characteristics

Table 6. DC Characteristics

T<sub>i</sub> = 25 ℃

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 3.36 \text{ mA}$	91.5	-	105.5	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS}$ = 20 V; $I_{D}$ = 336 mA	1.4	1.9	2.4	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 42 V	-	-	4.2	μА
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	50	59	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	420	nA
g <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 336 mA	51.6	-	-	mS
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 11.7 \text{ A}$	-	-	127	mΩ

#### Table 7. AC Characteristics

 $T_i = 25 \, ^{\circ}$ C

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 40 \text{ V}; f = 1 \text{ MHz}$	-	285	-	pF
C <sub>oss</sub>	output capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 40 V; f = 1 MHz	-	90	-	pF
C <sub>rss</sub>	reverse transfer capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 40 V; f = 1 MHz	-	3	-	pF

#### Table 8. RF characteristics

Test signal: pulsed RF;  $t_p$  = 1 ms;  $\delta$  = 10 %; RF performance at  $V_{DS}$  = 36 V;  $I_{Dq}$  = 150 mA;  $T_{case}$  = 25 °C; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_L$	output power		250	-	-	W
f <sub>range</sub>	frequency range		1200	-	1400	MHz
t <sub>p</sub>	pulse duration	δ = 10 %	-	-	1	ms
		δ = 20 %	-	-	100	μS
$\eta_{D}$	drain efficiency		42	45	-	%
t <sub>r</sub>	rise time	P <sub>L</sub> = 250 W [1]	-	-	200	ns
t <sub>f</sub>	fall time	P <sub>L</sub> = 250 W [1]	-	-	200	ns
Gp	power gain		13	15	-	dB
P <sub>droop(pulse)</sub>	pulse droop power		-	-	0.6	dB
RLin	input return loss		-	-	-7	dB

<sup>[1]</sup> The rise and fall time of the input circuit will be 5 ns maximum.

### 7. Test information

#### 7.1 Ruggedness in class-AB operation

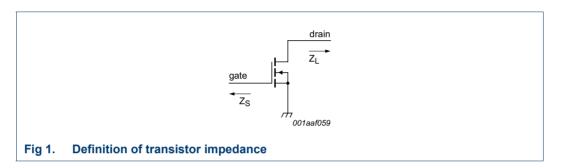
The BLL6G1214L-250 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 36 V;  $I_{Dq}$  = 150 mA;  $P_{L}$  = 250 W;  $t_{p}$  = 1 ms;  $\delta$  = 10 %.

### 7.2 Impedance information

Table 9. Typical impedance

Typical values unless otherwise specified.

f	Zs	Z <sub>L</sub>
(GHz)	(Ω)	(Ω)
1.2	1.077 – j2.78	1.288 – j1.014
1.3	1.352 – j2.949	1.139 – j1.086
1.4	1.881 – j2.640	1.038 – j1.132



### 7.3 Circuit information

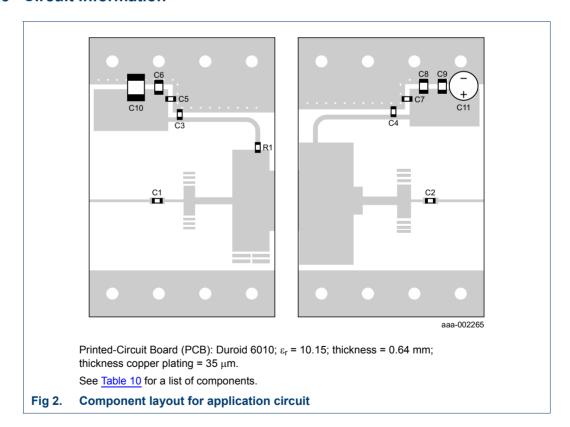


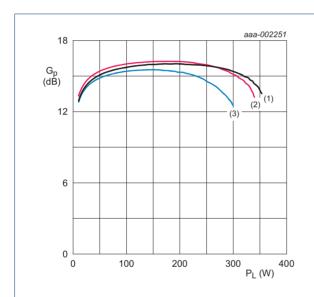
Table 10. List of components

For test circuit see Figure 2.

Component	Description	Value	Remarks
C1, C2, C3, C4, C7	multilayer ceramic chip capacitor	56 pF [1]	
C5, C8	multilayer ceramic chip capacitor	200 pF [2]	
C6, C9	multilayer ceramic chip capacitor	1 nF [3]	
C10	multilayer ceramic chip capacitor	10 μF, 20 V	
C11	electrolytic capacitor	22 μF, 63 V	
R1	resistor	10 Ω	SMD 0603

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- [2] American Technical Ceramics type 100B or capacitor of same quality.
- [3] American Technical Ceramics type 700A or capacitor of same quality.

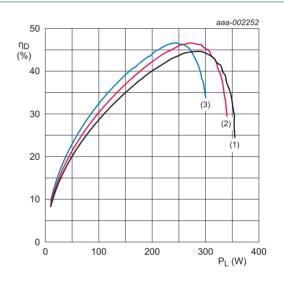
### 7.4 Graphical data



 $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %;  $T_h$  = 25 °C.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

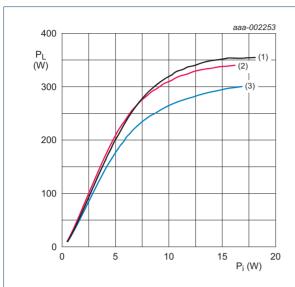
Fig 3. Power gain as a function of output power; typical values



 $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %;  $T_h$  = 25 °C.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

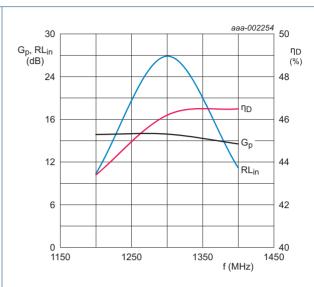
Fig 4. Drain efficiency as a function of output power; typical values



 $t_p = 100 \ \mu s; \ \delta = 10 \ \%; \ T_h = 25 \ ^{\circ}C.$ 

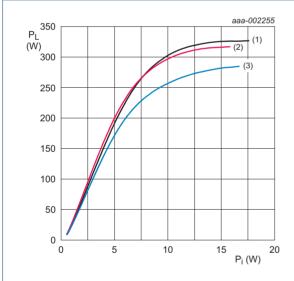
- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

Fig 5. Output power as a function of input power; typical values



$$P_L$$
 = 250 W;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %;  $T_h$  = 25 °C.

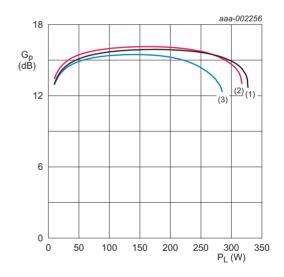
Fig 6. Power gain, input return loss and drain efficiency as function of frequency; typical values



 $t_p$  = 1 ms;  $\delta$  = 10 %;  $T_h$  = 25 °C.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

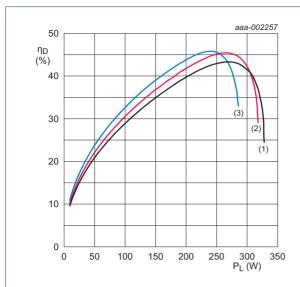
Fig 7. Output power as a function of input power; typical values



 $t_p$  = 1 ms;  $\delta$  = 10 %;  $T_h$  = 25 °C.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

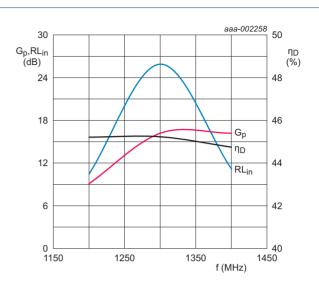
Fig 8. Power gain as a function of output power; typical values



 $t_p = 1 \text{ ms}; \delta = 10 \text{ %}; T_h = 25 \text{ °C}.$ 

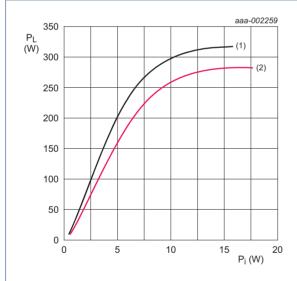
- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

Fig 9. Drain efficiency as a function of output power; typical values



 $P_L$  = 250 W;  $t_p$  = 1 ms;  $\delta$  = 10 %;  $T_h$  = 25 °C.

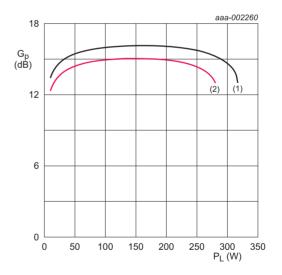
Fig 10. Power gain, input return loss and drain efficiency as function of frequency; typical values



 $f = 1300 \text{ MHz}; t_p = 1 \text{ ms}; \delta = 10 \%.$ 

- (1) T<sub>h</sub> = 25 °C
- (2)  $T_h = 85 \, ^{\circ}C$

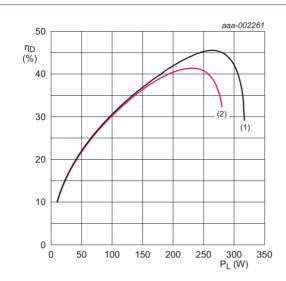
Fig 11. Output power as a function of input power; typical values



f = 1300 MHz;  $t_p = 1 \text{ ms}$ ;  $\delta = 10 \%$ .

- (1)  $T_h = 25 \, ^{\circ}C$
- (2)  $T_h = 85 \, ^{\circ}C$

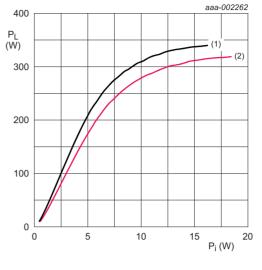
Fig 12. Power gain as a function of output power; typical values



f = 1300 MHz;  $t_p = 1 \text{ ms}$ ;  $\delta = 10 \%$ .

- (1)  $T_h = 25 \,^{\circ}C$
- (2)  $T_h = 85 \, ^{\circ}C$

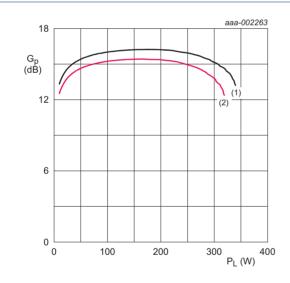
Fig 13. Drain efficiency as a function of output power; typical values



f = 1300 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %.

- (1)  $T_h = 25 \, ^{\circ}C$
- (2)  $T_h = 85 \, ^{\circ}C$

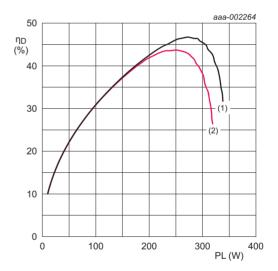
Fig 14. Output power as a function of input power; typical values



f = 1300 MHz;  $t_p = 1 \text{ ms}$ ;  $\delta = 10 \%$ .

- (1) T<sub>h</sub> = 25 °C
- (2)  $T_h = 85 \,^{\circ}C$

Fig 15. Power gain as a function of output power; typical values



f = 1300 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %.

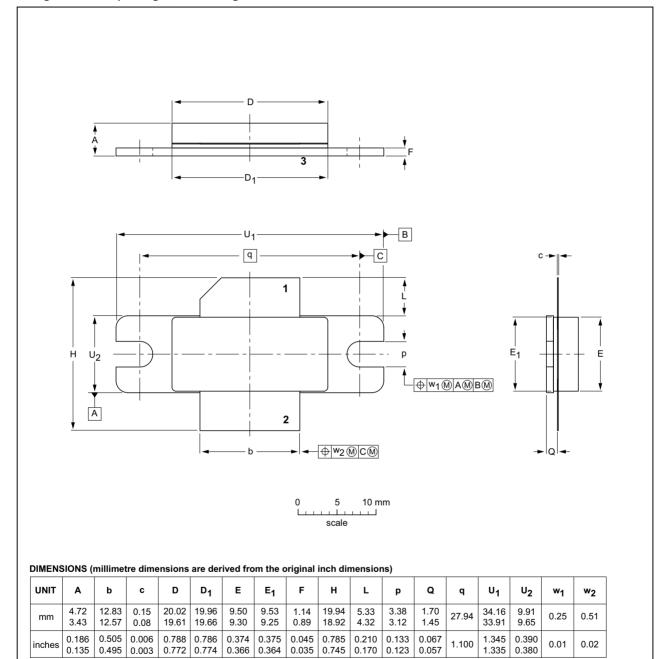
- (1)  $T_h = 25 \, ^{\circ}C$
- (2)  $T_h = 85 \, ^{\circ}C$

Fig 16. Drain efficiency as a function of output power; typical values

#### Package outline 8.

#### Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A



OUTLINE		REFER	RENCES	EUROPEAN	ICCUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT502A					<del>-03-01-10 -</del> 12-05-02	

Fig 17. Package outline SOT502A

## 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

### 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
IR	InfraRed
L-band	Long wave band
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio

### 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLL6G1214L-250 v.3	20160128	Product data sheet	-	BLL6G1214L-250_ 1214LS-250 v.2	
Modifications	The document now describes only the eared version of this product: BLL6G1214L-250				
BLL6G1214L-250_1214LS-250 v.2	20130624	Product data sheet	-	BLL6G1214L-250 v.1	
BLL6G1214L-250 v.1	20120216	Preliminary data sheet	-	-	

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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# **AMPLEON**

# BLL6G1214L-250

### **LDMOS L-band radar power transistor**

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